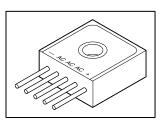
TECHNICAL DATA DATA SHEET 1135, REV, B

# THREE PHASE FULL WAVE BRIDGE RECTIFIER ASSEMBLY

DESCRIPTION: A 600 VOLT, 30 AMP, 5000 NANOSECOND THREE PHASE BRIDGE RECTIFIER ASSEMBLY.

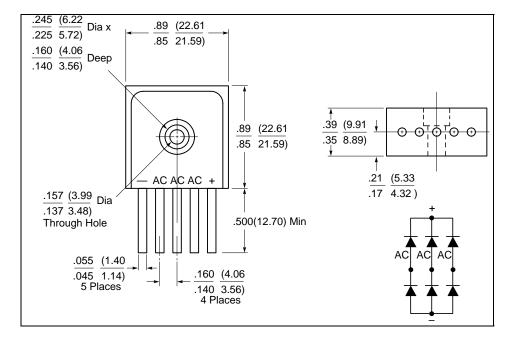
**MAX. RATINGS / ELECTRICAL CHARACTERISTICS** All ratings are at  $T_A = 25^{\circ}$ C unless otherwise specified.

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage	-	-	-	600	Vdc
(PIV)					
Average DC Output Current (T <sub>c</sub> = Case Temp) (I <sub>o</sub> )	T <sub>C</sub> = 55 °C	-	-	30	Amps
	T <sub>C</sub> = 100 °C			20	
Peak Single Cycle Surge Current (I <sub>FSM</sub> )	t <sub>p</sub> = 8.3 ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	100	Amps(pk)
Peak Recurring Surge Current (I <sub>FRM</sub> )	$T_A = 25 ^{\circ}C$	-	-	35	Amps
Operating and Storage Temp. (T <sub>op</sub> & T <sub>stg</sub> )	-	-55	-	+150	°C
Maximum Forward Voltage Per Leg (V <sub>f</sub> )	l <sub>f</sub> = 9.0Adc (300 μsec pulse, duty cycle < 2%)	-	-	1.4	Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	$T_A = 25^\circ C$	-	-	5.0	μAmps
	$T_A = 100^\circ C$			100	
Reverse Recovery Time (t <sub>rr</sub> )	$I_f = 0.5A, I_r = 1.0A;$ $I_{rr} = 0.25A$	-	-	5000	nsec
	Measured on discrete rectifiers prior to assembly.				
Max. Thermal Resistance $(R\theta_{JC})$	-	-	-	1.25	°C/W





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## **MECHANICAL DIMENSIONS: In Inches / mm**

## Fig. 455

#### Note: Case finish - Black Anodized

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